

## 5 é / Descriptions

TO-247 .&gt; // x Í Ů õ E â ³ } 'ož

Insulated-Gate Bipolar Transistor in a TO-247 Plastic Package.

## □ ª / Features

650V k 75A

 $V_{CE(SAT)} = 1.90V(\text{typ.}) @ V_{GE} = 15V, I_C = 75A$ 

## Đ ÷ / Applications

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Solar Converters, Uninterrupted Power Supply, Welding Converters, Mid to High Range Switching Frequency Converters.

## Ã W ] Ô • / Equivalent Circuit

## • Ů - æ / Pinning

PIN1 y G

PIN 2o•EPAD y C

PIN 3 y E

## , M V / Marking

• - ~ ª ¢ ož

See Marking Instructions.

| @ f<br>Parameter                                        |                     | ... Z<br>Symbol  | f ><br>Rating | % y<br>Unit |
|---------------------------------------------------------|---------------------|------------------|---------------|-------------|
| Collector-Emitter Voltage                               |                     | V <sub>CES</sub> | 650           | V           |
| Gate-Emitter Voltage                                    |                     | V <sub>GES</sub> | f 30          | V           |
| Continuous Collector Current                            | T <sub>C</sub> =25  | I <sub>C</sub>   | 150           | A           |
|                                                         | T <sub>C</sub> =100 |                  | 75            | A           |
| Pulsed Collector Current , Limited by T <sub>Jmax</sub> |                     | I <sub>CM</sub>  | 300           | A           |
| Continuous Diode Forward Current                        | T <sub>C</sub> =25  | I <sub>F</sub>   | 160           | A           |
|                                                         | T <sub>C</sub> =100 |                  | 80            | A           |
| Power Dissipation                                       | T <sub>C</sub> =25  | P <sub>D</sub>   | 750           | W           |
|                                                         | T <sub>C</sub> =100 |                  | 375           | W           |
| Operating Junction Temperature Range                    |                     | T <sub>J</sub>   | -40 to +175   |             |
| Storage Temperature Range                               |                     | T <sub>STG</sub> | -55 to +150   |             |
| Maximum Junction-to-Ambient                             |                     | R <sub>JA</sub>  | 80            | /W          |
| Maximum IGBT Junction-to-Case                           |                     | R <sub>JC</sub>  | 0.24          | /W          |
| Maximum Diode Junction-to-Case                          |                     | R <sub>JC</sub>  | 0.48          | /W          |

| @ f<br>Parameter                     | ... Z<br>Symbol      | y i Ú ^<br>Test Conditions                               | Â 4 ><br>Min        | Á ° ><br>Typ | Â Ý ><br>Max | % y<br>Unit |
|--------------------------------------|----------------------|----------------------------------------------------------|---------------------|--------------|--------------|-------------|
| Collector-Emitter Breakdown Voltage  | BV <sub>CES</sub>    | I <sub>C</sub> =250uA, V <sub>GE</sub> =0V               | 650                 |              |              | V           |
| Zero Gate Voltage Collector current  | I <sub>CES</sub>     | V <sub>CE</sub> =650V, V <sub>GE</sub> =0V               |                     |              | 250          | uA          |
| Gate-Emitter Leakage Current         | I <sub>GES</sub>     | V <sub>CE</sub> =0V, V <sub>GE</sub> = ±30V              |                     |              | f 100        | nA          |
| Gate-Emitter Threshold Voltage       | V <sub>GE(th)</sub>  | V <sub>CE</sub> =V <sub>GE</sub> , I <sub>C</sub> =250 A | 4.0                 | 5.0          | 5.5          | V           |
| Collector-Emitter Saturation Voltage | V <sub>CE(sat)</sub> | V <sub>GE</sub> =15V, I <sub>C</sub> =75A                | T <sub>J</sub> =25  | 1.90         | 2.20         | V           |
|                                      |                      |                                                          | T <sub>J</sub> =125 | 2.00         |              |             |

Total Gate Charge

Q<sub>g</sub> CEW (CES)T 10.4958 0 0 10.5 351.24 72217 250Tm -.0002 Tc (=1onV01

| Parameter              | Symbol       | Test Conditions                                                              | Min          | Typ  | Max  | Unit |
|------------------------|--------------|------------------------------------------------------------------------------|--------------|------|------|------|
| Turn-On Delay Time     | $t_{d(on)}$  | $V_{GE}=15V$ ,<br>$V_{CC}=400V$<br>$I_C=75A$ ,<br>$R_G=10$<br>Inductive Load | TC=25        | 38   |      | ns   |
|                        |              |                                                                              | Tc=150       | 36   |      | ns   |
| Turn-On Rise Time      | $t_r$        |                                                                              | TC=25        | 118  |      | ns   |
|                        |              |                                                                              | Tc=150       | 100  |      | ns   |
| Turn-Off Delay Time    | $t_{d(off)}$ |                                                                              | TC=25        | 267  |      | ns   |
|                        |              |                                                                              | Tc=150       | 300  |      | ns   |
| Turn-Off Fall Time     | $t_f$        |                                                                              | TC=25        | 81   |      | ns   |
|                        |              |                                                                              | Tc=150       | 85   |      | ns   |
| Turn-On Energy         | $E_{on}$     |                                                                              | TC=25        | 4.65 |      | mJ   |
|                        |              |                                                                              | Tc=150       | 4.50 |      | mJ   |
| Turn-Off Energy        | $E_{off}$    |                                                                              | TC=25        | 2.45 |      | mJ   |
|                        |              |                                                                              | Tc=150       | 2.70 |      | mJ   |
| Total Switching Energy | $E_{ts}$     |                                                                              | TC=25        | 7.10 |      | mJ   |
|                        |              |                                                                              | Tc=150       | 7.20 |      | mJ   |
| Input Capacitance      | $C_{ies}$    | $V_{GE}=0V$ ,<br>$f=1MHz$                                                    | $V_{CE}=25V$ |      | 2850 | pF   |

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Ø □ = ) ¢ / Package Dimensions

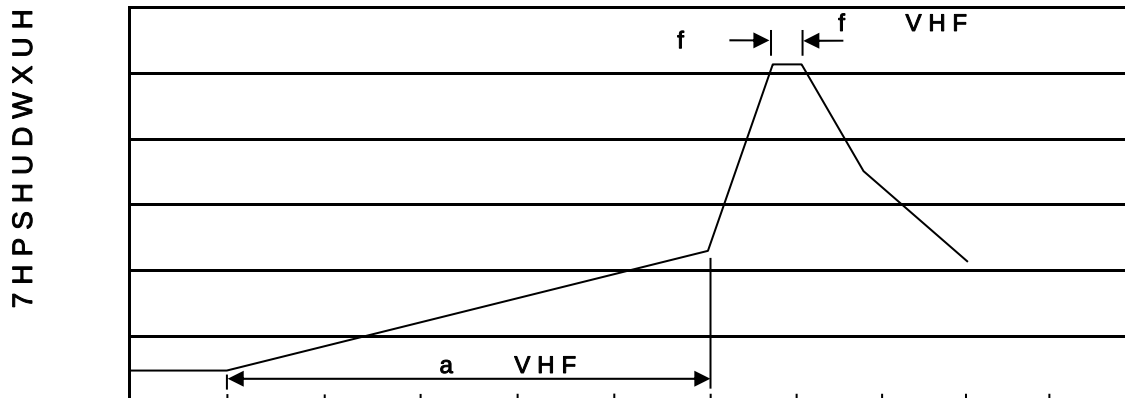
, M y f / Marking Instructions

BR  
GB75P65AHA  
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<sup>a</sup> ¢ y  
BR y , [ W A  
- ( 6 ' . ' y ° Z W A  
y ÿ D Z W A k š ÿ D Z J

Note:  
BR: Company Code  
GB75P65AHA: Product Type Code  
\*\*\*\*: Lot No. Code, code change with Lot No.

## G PD t ... • Ž Ć ( x / ) / Temperature Profile for Dip Soldering(Pb-Free)



## 7LPH VHF

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1o• Ä ½ "† 25 ½150 - k ž • 60 ½90sec;

2o• Q &gt; "† 255 r5 - k ž • 4 Ò 5 r0.5sec;

3o•D N ò i Ò 0 ,† 2 ½10 - /sec.

Note:

1.Preheating:25~150 - , Time:60~90sec.

2.Peak Temp.:255 r5 - , Duration:5 r0.5sec.

3. Cooling Speed: 2~10 - /sec.

## ÂD /Că p - »] / Resistance to Soldering Heat Test Conditions

"† y 270 r5 -

ž • y 10 r1 sec.

Temp.:270±5

Time:10±1 sec

## G P á / Packaging SPEC.

ì' x / TUBE

| Package Type<br>7>û ~ E | Units ;>û !H       |                           |                       |                                |                        | Dimension ;>û p . (unit 4mm³) |            |             |
|-------------------------|--------------------|---------------------------|-----------------------|--------------------------------|------------------------|-------------------------------|------------|-------------|
|                         | Units/Tube<br>/•1× | Tubes/Inner Box<br>•1× /- | Units/Inner Box<br>/- | Inner Boxes/Outer Box<br>- /1ç | Units/Outer Box<br>/1ç | Tube•1×                       | Inner Box  | Outer Boxç  |
| TO-247                  | 30                 | 15                        | 450                   | 5                              | 2250                   | 520×44×6                      | 580×158×55 | 595×300×178 |

## „Đ y f / Notices

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